



## 2N4117/A, 2N4118/A, 2N4119/A N-Channel JFET

Technical

Drain

Source

Support

Order

Now

#### **Features**

- InterFET N0001H Geometry
- Low Leakage: 0.25 pA Typical
- Low Input Capacitance: 2.0 pF Typical
- High Input Impedance
- RoHS Compliant
- SMT, TH, and Bare Die Package options.

#### Applications

- Low Leakage Input Buffer
- High Frequency Amplifier/Buffer
- Ultrahigh Impedance Pre-Amplifier
- Voltage Controlled Resistor
- Current Limiters and Regulators

#### Description

The -50V InterFET 2N4117/A, 2N4118/A, and 2N4119/A JFET's are targeted for ultra high input impedance applications for mid to high frequency designs. Gate leakages are typically 1pA at room temperatures. The 2N4117 has a cutoff voltage of less than 1.8V ideal for low-level power supplies. The TO-72 package is hermetically sealed and suitable for military applications.

#### **Product Summarv**

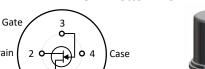
	Parameters	2N4117/A Min	2N4118/A Min	2N4119/A Min	Unit
BV <sub>GSS</sub>	Gate to Source Breakdown Voltage	-40	-40	-40	V
IDSS	Drain to Source Saturation Current	0.03	0.08	0.2	mA
V <sub>GS(off)</sub>	Gate to Source Cutoff Voltage	-0.6	-1	-2	V
GFS	Forward Transconductance	70	80	100	μS

#### Ordering Information Custom Part and Binning Options Available

Part Number	Description	Case	Packaging
2N4117; 2N4118; 2N4119			
2N4117A; 2N4118A; 2N4119A	Through-Hole	TO-72	Bulk
PN4117; PN4118; PN4119			
PN4117A; PN4118A; PN4119A	Through-Hole	TO-92	Bulk
SMP4117; SMP4118; SMP4119			
SMP4117A; SMP4118A; SMP4119A	Surface Mount	SOT23	Bulk
SMP4117TR; SMP4118TR; SMP4119TR	7" Tape and Reel: Max 3,000 Pieces		Minimum 1,000 Pieces
SMP4117ATR; SMP4118ATR; SMP4119ATR	13" Tape and Reel: Max 9,000 Pieces	SOT23	Tape and Reel
	Chip Orientated Tray		
2N4117COT; 2N4118COT; 2N4119COT	(COT Waffle Pack)	СОТ	400/Waffle Pack
	Chip Face-up Tray		
2N4117CFT; 2N4118CFT; 2N4119CFT	(CFT Waffle Pack)	CFT	400/Waffle Pack

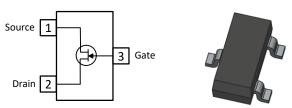


Disclaimer: It is the Buyers responsibility for designing, validating and testing the end application under all field use cases and extreme use conditions. Guaranteeing the application meets required standards, regulatory compliance, and all safety and security requirements is the responsibility of the Buyer. These resources are subject to change without notice.

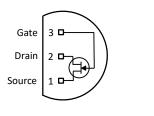














### **TO-72 Bottom View**







### **Electrical Characteristics**

#### Maximum Ratings (@ T<sub>A</sub> = 25°C, Unless otherwise specified)

	Parameters	Value	Unit
VRGS	Reverse Gate Source and Gate Drain Voltage	-40	V
$I_{FG}$	Continuous Forward Gate Current	50	mA
PD	Continuous Device Power Dissipation	300	mW
Р	Power Derating	2	mW/°C
Τı	Operating Junction Temperature	-55 to 125	°C
T <sub>STG</sub>	Storage Temperature	-65 to 150	°C

Support

### Static Characteristics (@ TA = 25°C, Unless otherwise specified, Highlighted values = A variant)

			2N4117/A		2N4118/A		2N4119/A		
	Parameters	Conditions	Min	Max	Min	Max	Min	Max	Unit
V(BR)GSS	Gate to Source Breakdown Voltage	$I_G = -1\mu A, V_{DS} = 0V$	-40		-40		-40		V
	Gate to Source	V <sub>GS</sub> = -20V, V <sub>DS</sub> = 0V		-10		-10		-10	pА
lgss	Reverse Current			-1		-1		-1	pА
Vgs(off)	Gate to Source Cutoff Voltage	V <sub>DS</sub> = 10V, I <sub>D</sub> = 1nA	-0.6	-1.8	-1	-3	-2	-6	V
	Drain to Source	$V_{DS} = 10V, V_{GS} = 0V$	0.03	0.09	0.08	0.24	0.2	0.6	mA
I <sub>DSS</sub>	Saturation Current	(Pulsed)	0.015	0.09	0.08	0.24	0.2	0.6	mA

### Dynamic Characteristics (@ TA = 25°C, Unless otherwise specified)

			2N4117/A		2N4118/A		2N4119/A		
	Parameters	Conditions	Min	Max	Min	Max	Min	Max	Unit
G <sub>FS</sub>	Forward Transconductance	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1kHz	70	210	80	250	100	330	μS
Gos	Output Conductance	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1kHz		3		5		10	μS
Ciss	Input Capacitance	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1MHz		3		3		3	pF
C <sub>rss</sub>	Reverse Transfer Capacitance	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1MHz		1.5		1.5		1.5	pF



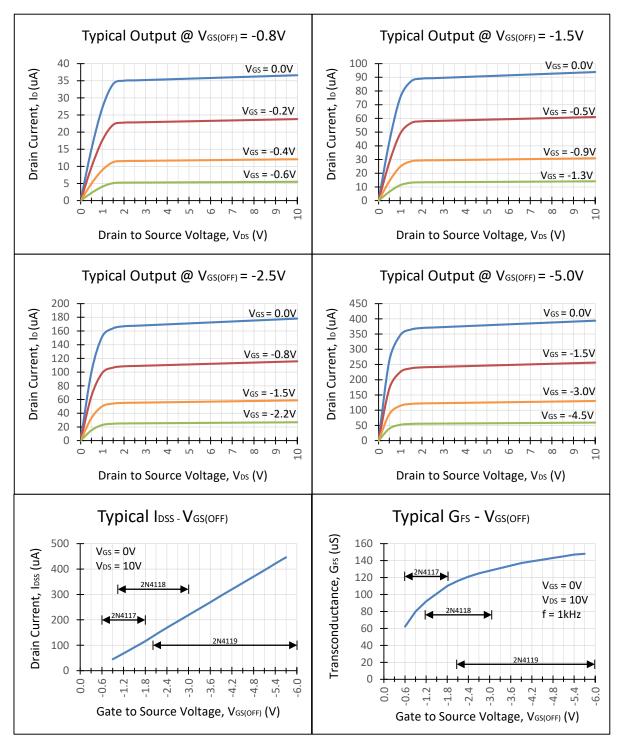
Order Now

Technical

Support

## 2N4117-8-9A

### Typical 2N4117, 2N4118, 2N4119 Characteristics







Technical

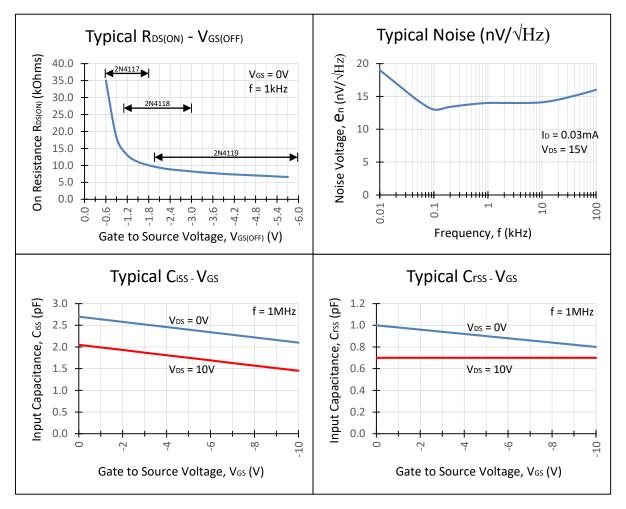
Support

Order

Now

2N4117-8-9A

### Typical 2N4117, 2N4118, 2N4119 Characteristics (Continued)





Technical

Support

Order

Now

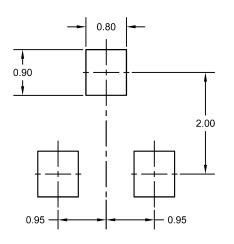
### SOT23 (TO-236AB) Mechanical and Layout Data

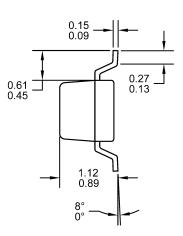
### Package Outline Data





### **Suggested Pad Layout**





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.12 grams
- 3. Molded plastic case UL 94V-0 rated
- For Tape and Reel specifications refer to InterFET CTC-021 Tape and Reel Specification, Document number: IF39002
- 5. Bulk product is shipped in standard ESD shipping material
- 6. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided for reference only. A more robust pattern may be desired for wave soldering.



Technical Support

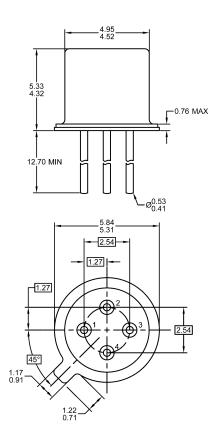
Order

Now

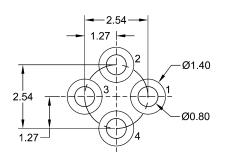
## 2N4117-8-9A

### **TO-72 Mechanical and Layout Data**

### **Package Outline Data**



### Suggested Through-Hole Layout



- 1. All linear dimensions are in millimeters.
- 2. Four leaded device. Not all leads are shown in drawing views.
- 3. Package weight approximately 0.31 grams
- 4. Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

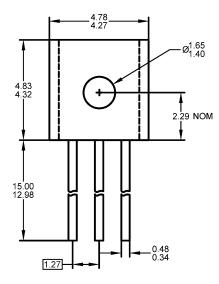


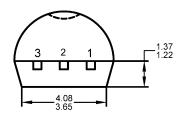
Technical Support Now

## 2N4117-8-9A

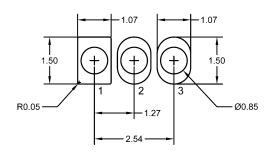
### **TO-92 Mechanical and Layout Data**

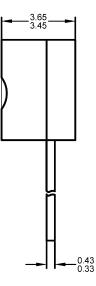
### **Package Outline Data**





### Suggested Through-Hole Layout





- 1. All linear dimensions are in millimeters.
- 2. Package weight approximately 0.19 grams
- 3. Molded plastic case UL 94V-0 rated
- 4. Bulk product is shipped in standard ESD shipping material
- 5. Refer to JEDEC standards for additional information.

- 1. All linear dimensions are in millimeters.
- 2. The suggested land pattern dimensions have been provided as a straight lead reference only. A more robust pattern may be desired for wave soldering and/or bent lead configurations.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for JFET category:

Click to view products by InterFET manufacturer:

Other Similar products are found below :

 MCH3914-8-TL-H
 F5606
 2SK2394-6-TB-E
 CPH5901G-TL-E
 MCH3914-7-TL-H
 MCH5908H-TL-E
 CPH5902G-TL-E
 CPH5905G-TL-E

 CPH5905H-TL-E
 2SK2394-7-TB-E
 NSVJ2394SA3T1G
 2N3819
 PN4393
 MMBFJ176
 2N4393
 U311
 2N5397
 2SK208-GR(TE85L,F)

 MMBF4393LT1G
 J176\_D74Z
 IF4500
 SMP4338
 SMP147
 SMP5116
 SMPJ232
 SMPJ310
 SMPJ4856
 IF1330
 SMPJ201

 SMP4340
 SMP5484
 IFN5566
 2N2609
 2N3821
 2N3970
 2N3971
 2N3972
 2N4091
 2N4092
 2N4093
 2N4118
 2N4221
 2N4221A

 2N4338
 2N4416
 2N4416A
 2N4856
 IFN5566
 2N4856
 IFN5566